

FJC690

Camera Strobe Flash Application

- Complement to FJC790
- High Collector Current
- Low Collector-Emitter Saturation Voltage



1. Base 2. Collector 3. Emitter

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

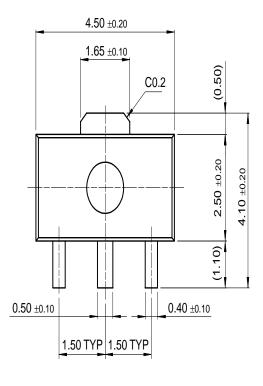
Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	45	V
V_{CEO}	Collector-Emitter Voltage	45	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	2	Α
P _C	Power Dissipation	0.5	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

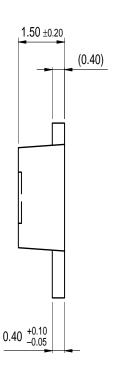
Electrical Characteristics T_a=25°C unless otherwise noted

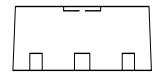
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	45			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 10 \text{mA}, I_B = 0$	45			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 100 \mu A, I_C = 0$	5			V
I _{CEO}	Collector Cut-off Current	$V_{CE} = 35V, V_{B} = 0$			0.1	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 4V, I_{C} = 0$			0.1	μΑ
h _{FE}	DC Current Gain	$V_{CE} = 2V, I_{C} = 100 \text{mA}$ $V_{CE} = 2V, I_{C} = 1 \text{mA}$ $V_{CE} = 2V, I_{C} = 2 \text{mA}$	500 400 150			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 0.1A, I_B = 0.5mA$ $I_C = 1A, I_B = 5mA$			80 300	mV mV
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 1A, I_B = 10mA$			0.9	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 2V$, $I_C = 1A$			0.85	V
C _{OB}	Collector Output Capacitance	$V_{CB} = 10V$, $I_E = 0$, $f = 1MHz$		20		pF

Package Dimensions

SOT-89







Dimensions in Millimeters

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